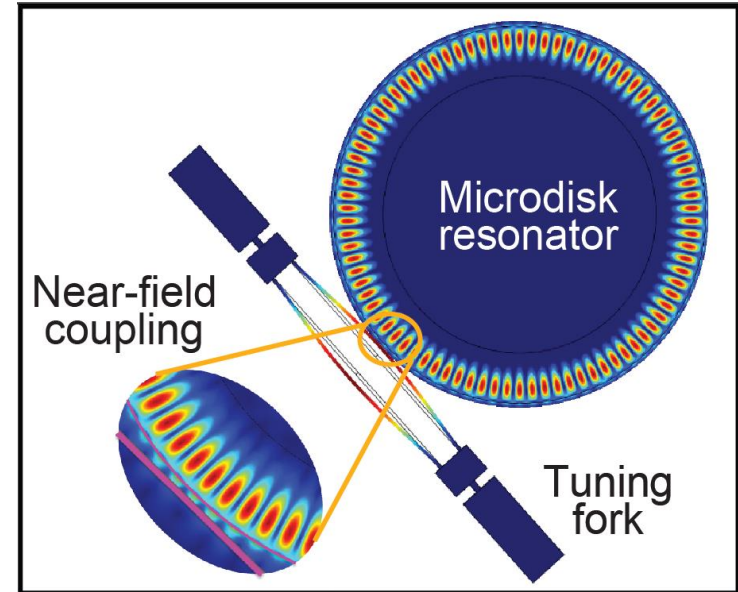
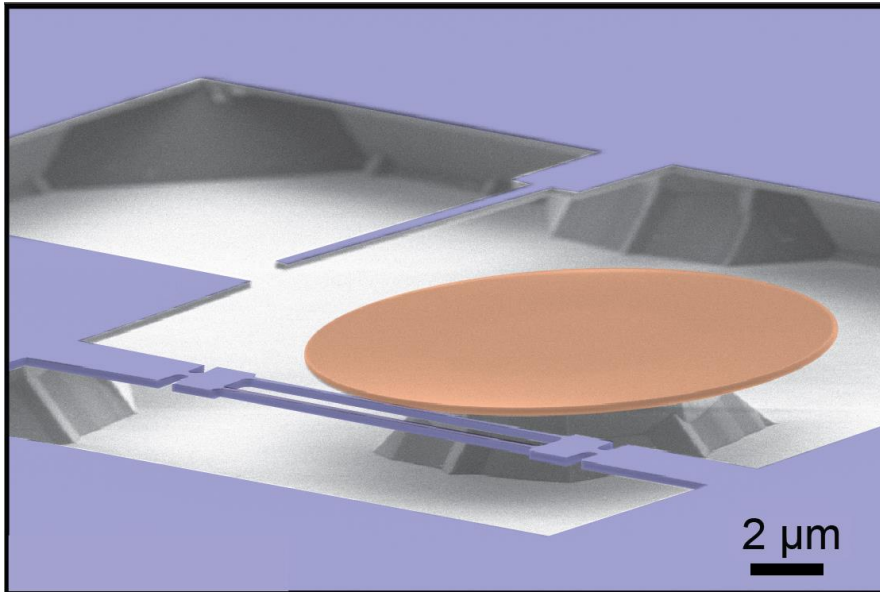


High mechanical $f_m Q_m$ product tuning fork cavity optomechanical transducers



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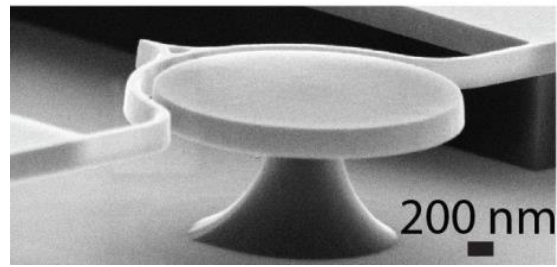
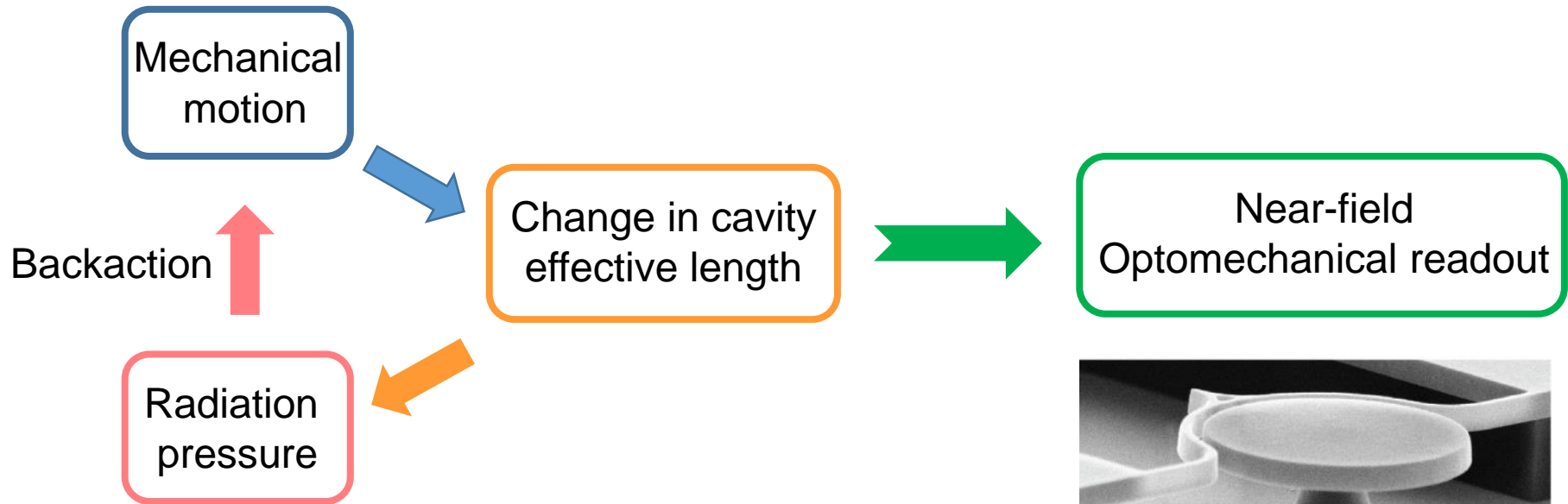
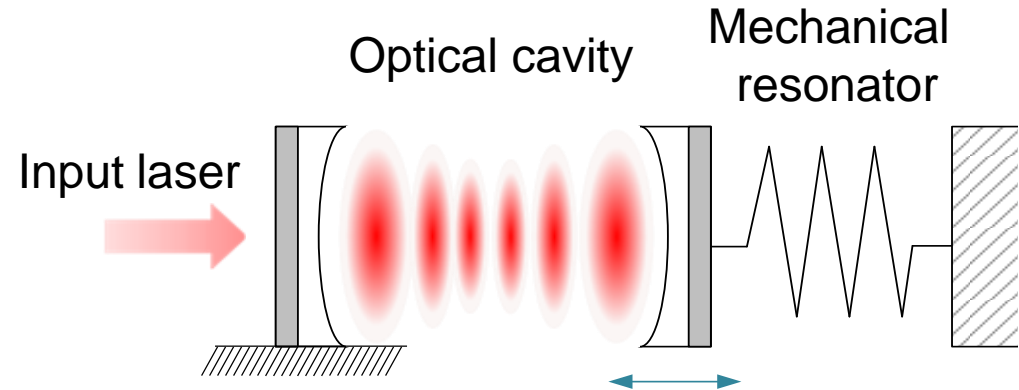
²Center for Nanoscale Science and Technology, National Institute of Standards and Technology, Gaithersburg, MD 20899, USA

Corresponding author: yliu11@wpi.edu

Outline

- **Background**
 - Cavity optomechanics
 - Cantilever-based optomechanical transducers
- **Motivation**
- **Device working principles, and test results**
 - Near-field optomechanical readout
 - Geometry-determined resonant frequency
 - Temperature compensation
- **Summary and future work**

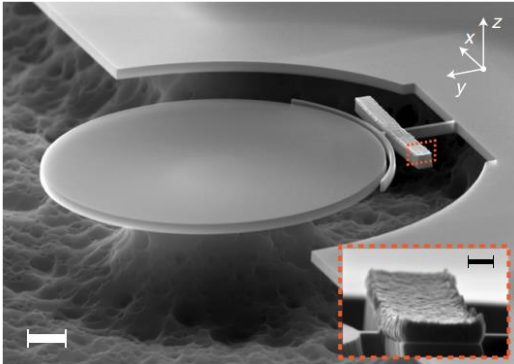
Cavity Optomechanics



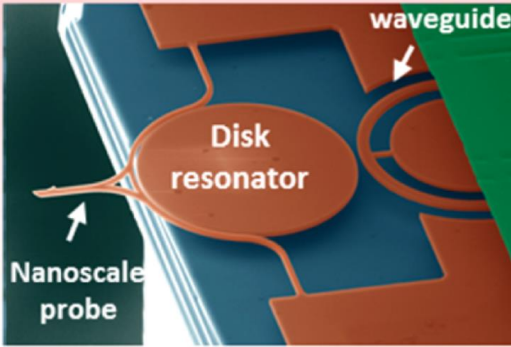
Opt. Express 20, 18268 (2012)

Cantilever-based Si₃N₄ Devices

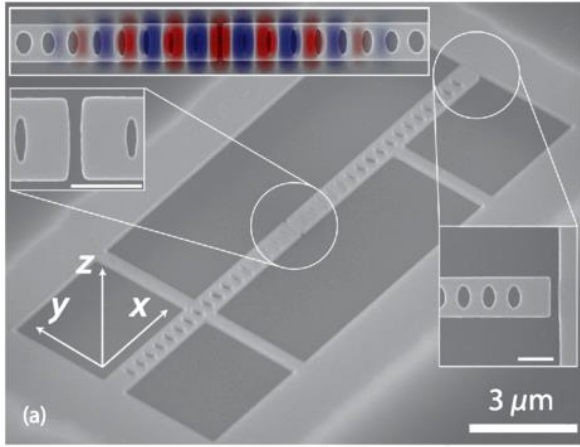
- Cantilever-based optomechanical devices
 - Separation between optical and mechanical resonator
 - Small mass
 - Moderate fundamental mechanical frequencies (MHz)
 - High sensitivity



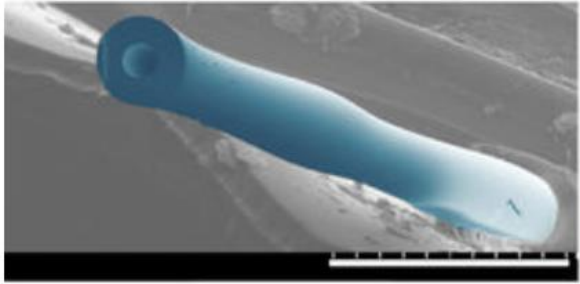
Nat. Commun. 1355 (2017)



Nano Lett., 2017, 17 (9), pp 5587–5594



Phys. Rev. X 4, 021052



Nat. Commun. 1994 (2013)

Motivation

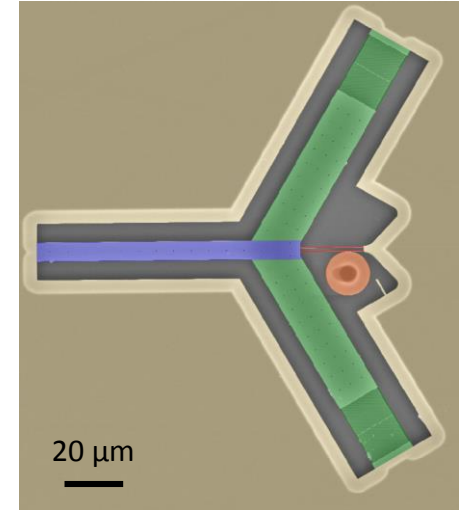
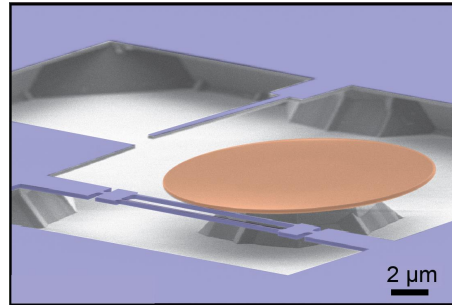
To develop a high-precision, low-drift displacement measurement platform for various precision MEMS sensor applications

➤ Enhanced transduction at small scales

- Frequency stability and limit of detection:
 $\langle \delta f/f_0 \rangle = (1/2Q)10^{-(DR/20)}$

➤ High mechanical $f_m Q_m$ product

- High bandwidth
- Force sensitivity scales as $1/(f_m^{0.5} Q_m^{0.5})$
- Overcome tradeoff between f_m and Q_m



➤ Si₃N₄ mechanical resonator with design-determined mechanical frequency

- Si₃N₄ intrinsic stress varies with different fabrication processes

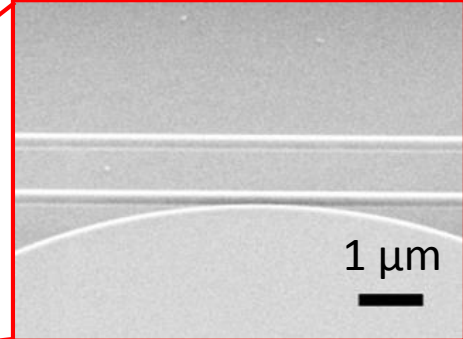
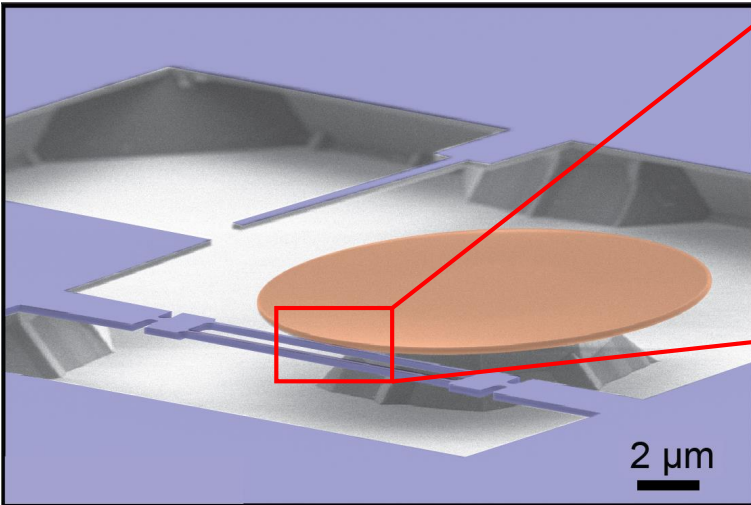
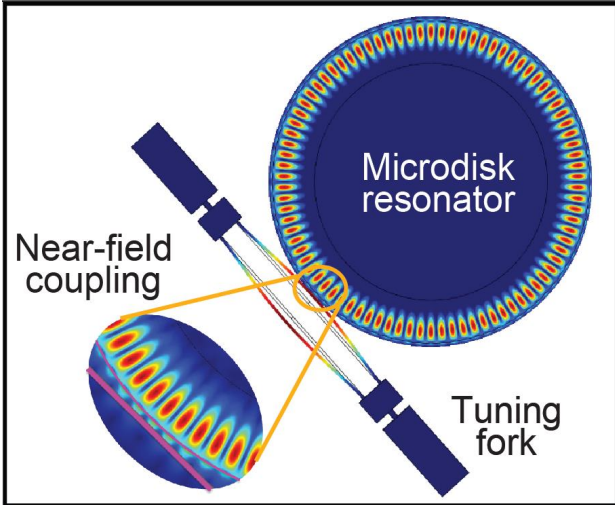
➤ Mechanical resonator with design-enabled temperature compensation

- Remove influence from temperature
- Not rely on matching different materials/in-situ active temperature control.

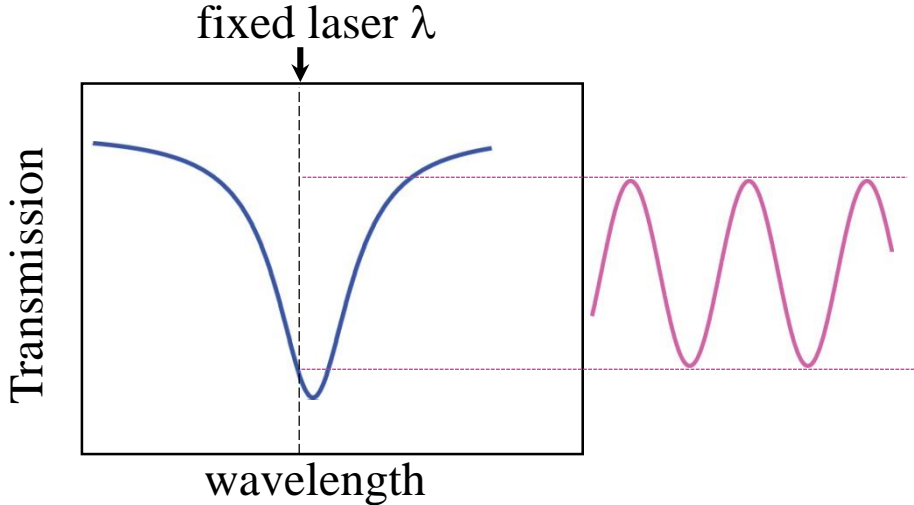
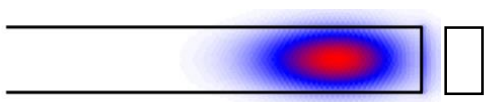
➤ Solution:

- Tuning fork optomechanical transducer with near-field readout and special nonlinear mechanical clamp design.

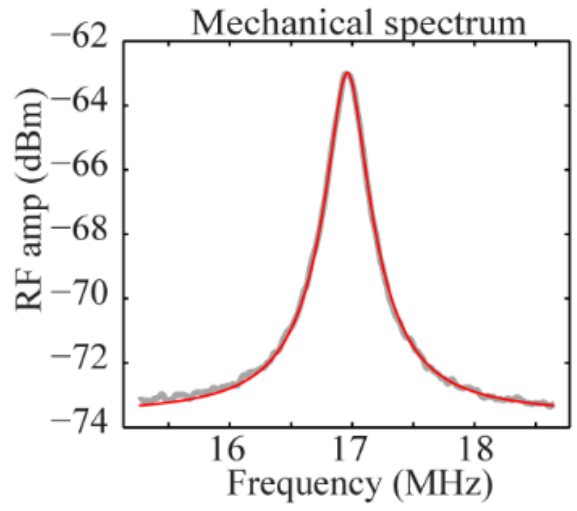
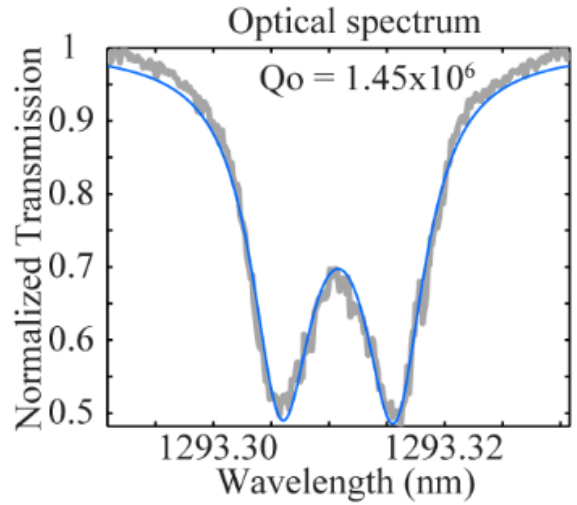
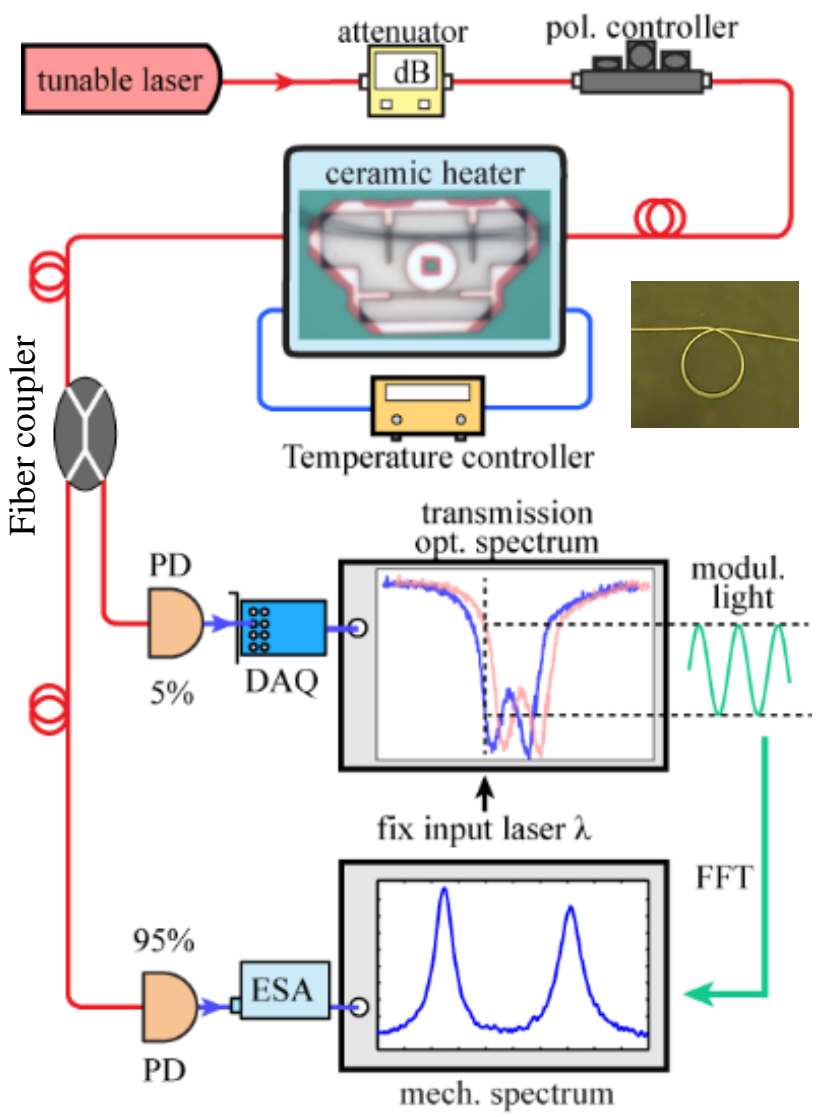
Near-field Optomechanical Readout



$$g_{OM}/2\pi = 140 \text{ MHz/nm}$$



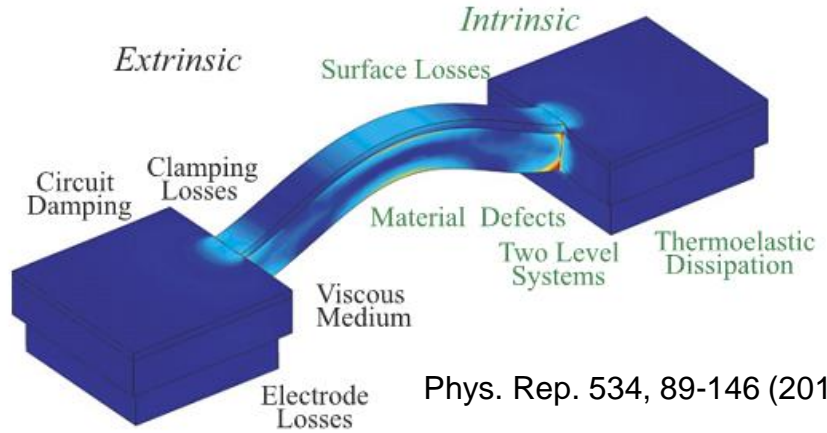
Device Characterization Setup



Random motion of a resonator driven by thermomechanical noise can be resolved

High $f_m Q_m$ Product – Tuning fork

- Loss for mechanical resonators operating in vacuum
- Thermoelastic dissipation (TED)
- Material loss
 - Volume loss
 - Surface loss
- Clamping loss



Phys. Rep. 534, 89-146 (2014)

$$1/Q_M = 1/Q_{clamping} + 1/Q_{TED} + 1/Q_{material} + 1/Q_{other}$$

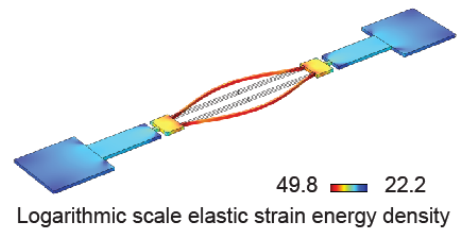
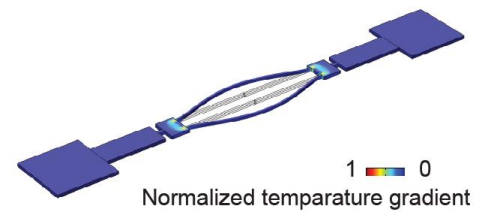
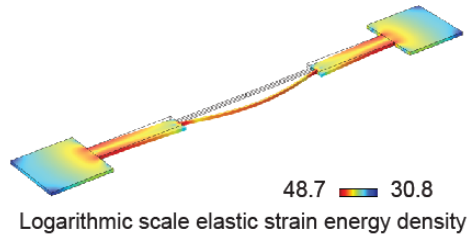
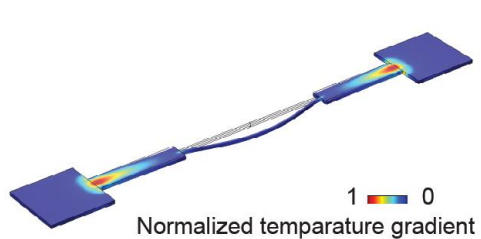
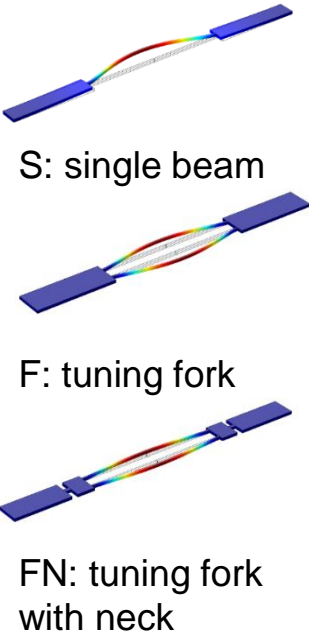
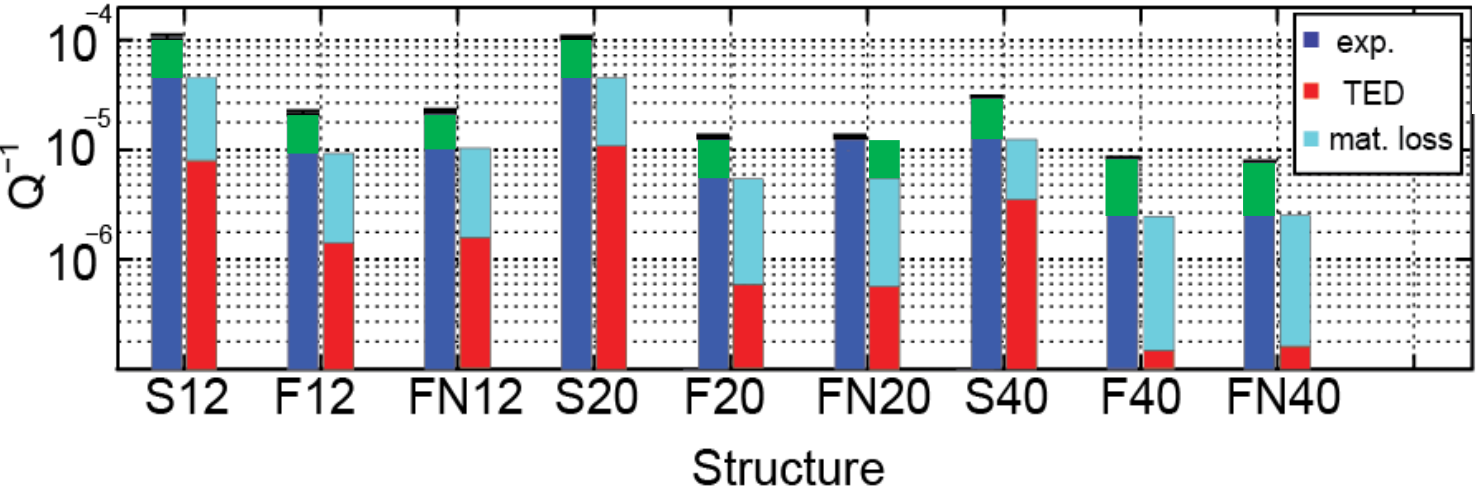
All these losses can be reduced by localized motion



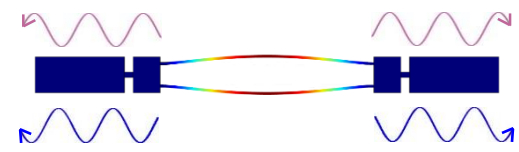
-15 0

Logarithmic scale normalized displacement

Localized Motion Reduces Mechanical Loss

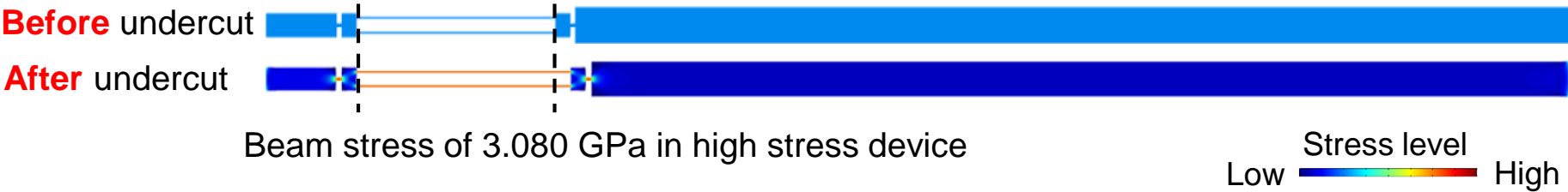
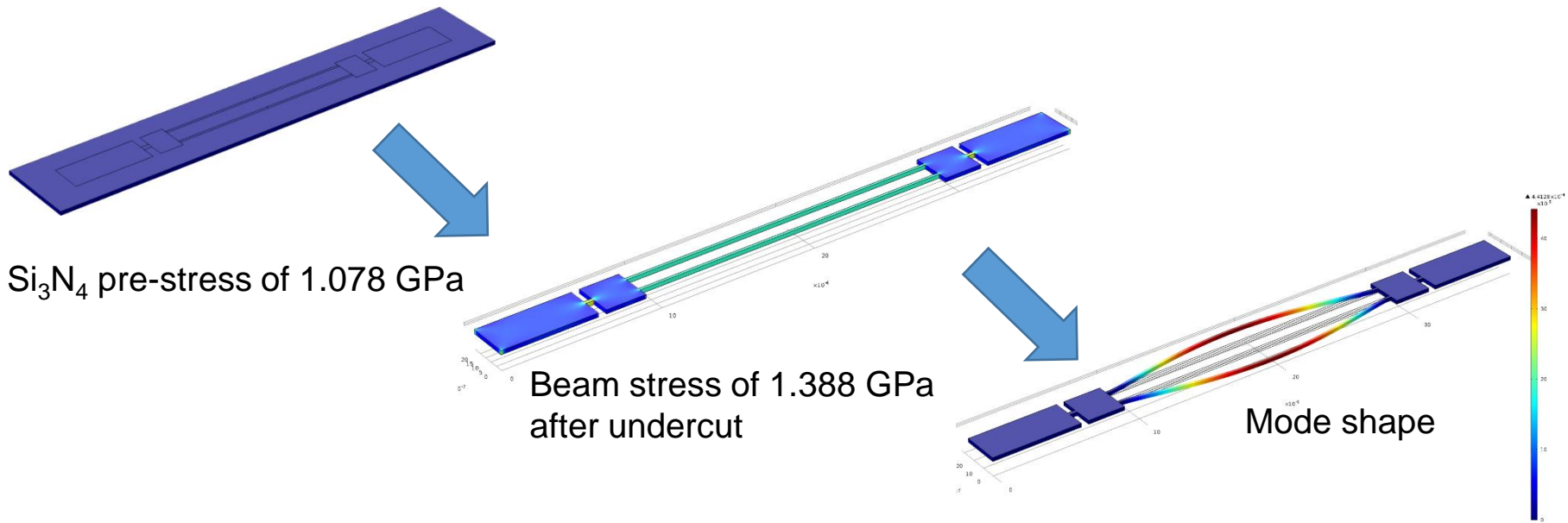


$$1/Q_{clamping} \approx 1/Q_M - 1/Q_{TED} - 1/Q_{material}$$

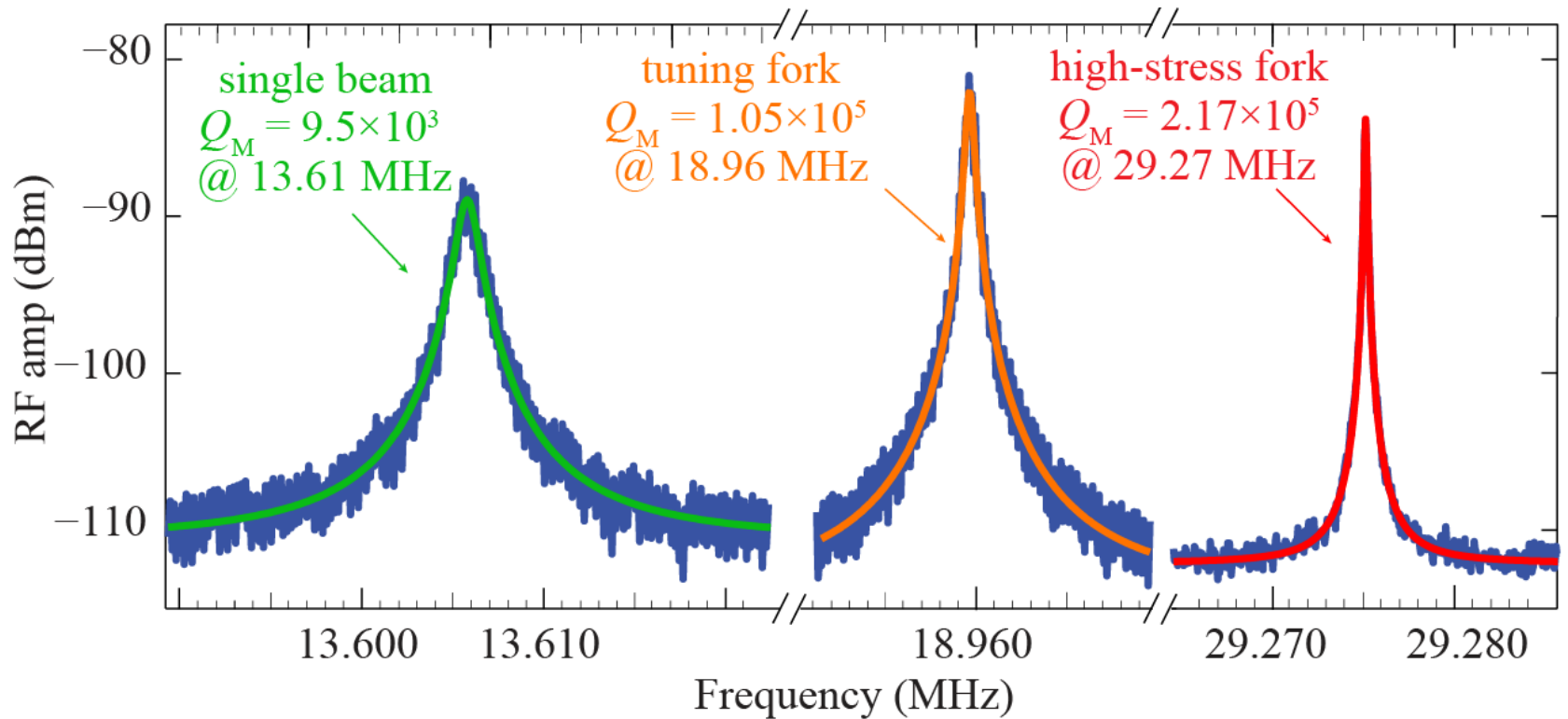
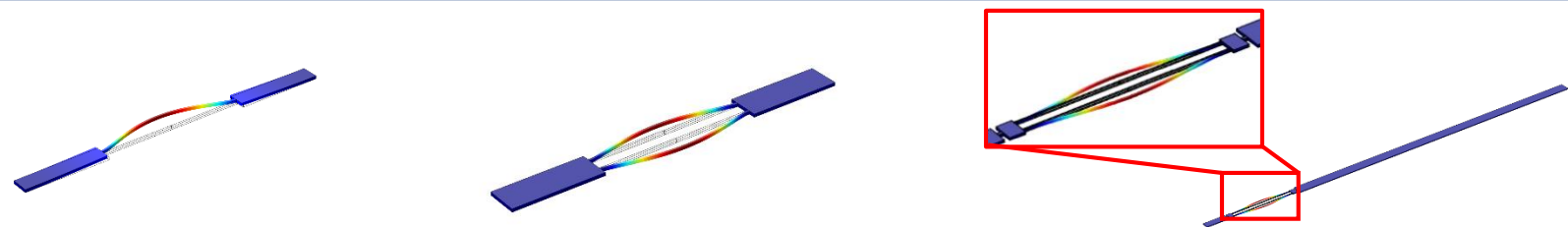


Stress Engineering

- Doubly clamped Si_3N_4 tuning forks with a high tensile stress
 - LPCVD Si_3N_4 has high intrinsic tensile stress uniformly distributed
 - The stress retained with doubly clamped tuning forks but redistributed
 - Final beam stress/frequency can be engineered without reduction of Q_m

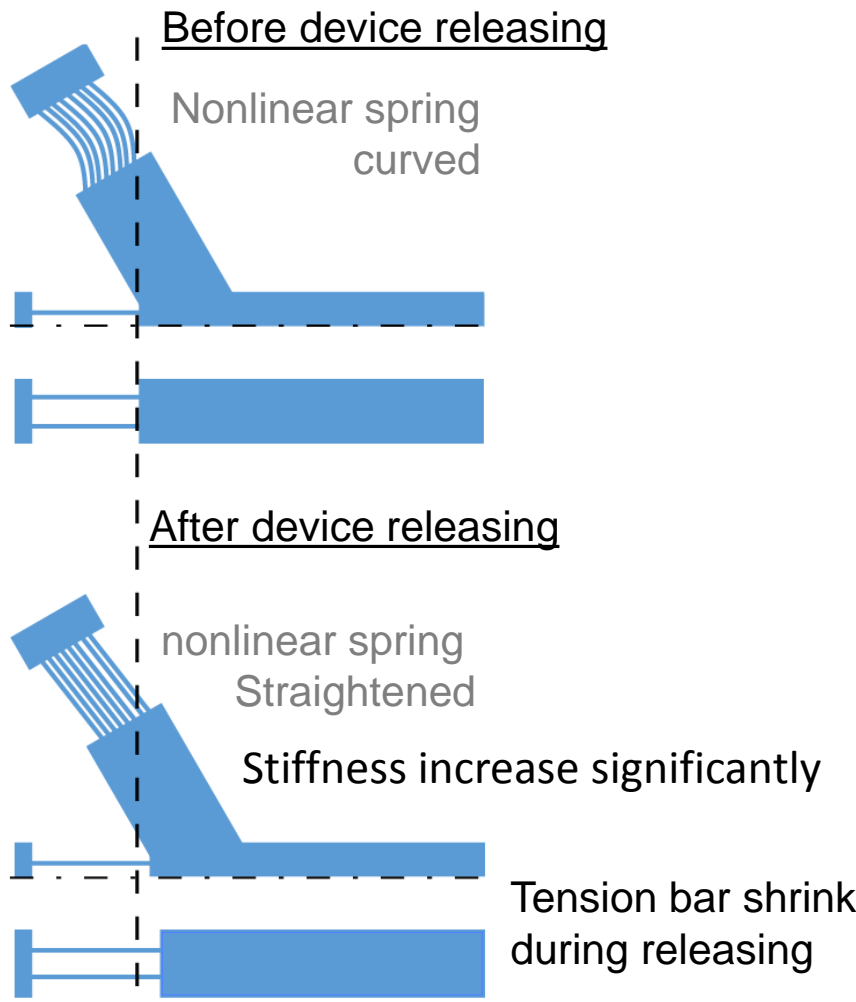
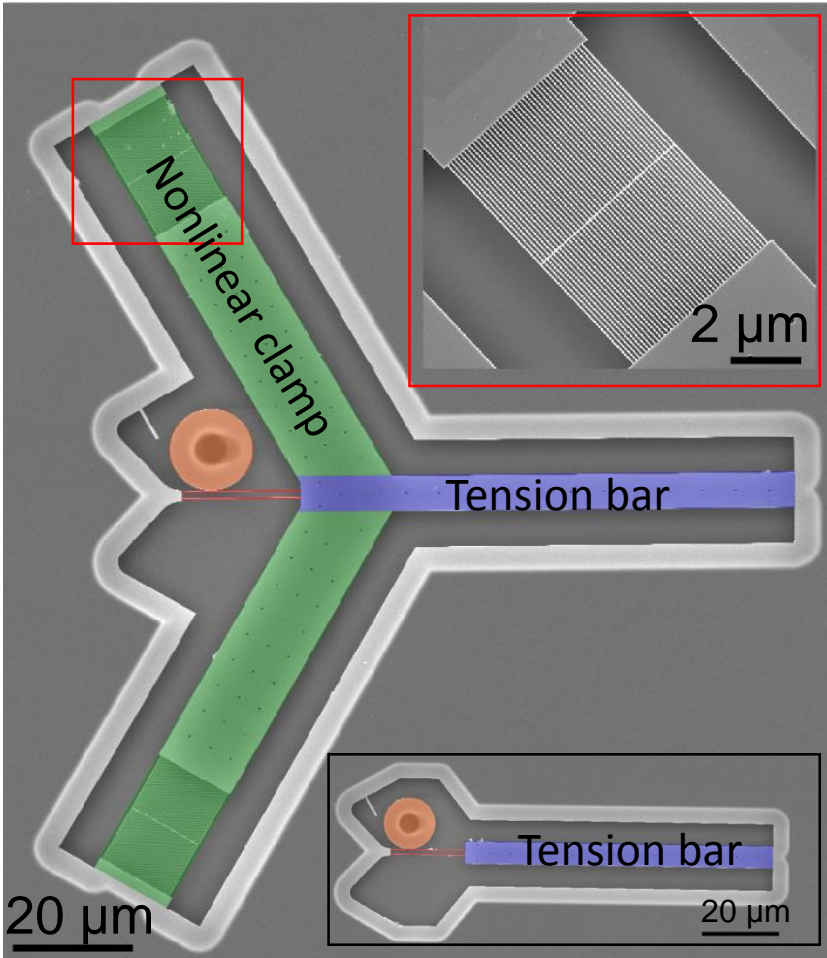


Measured Mechanical Spectra

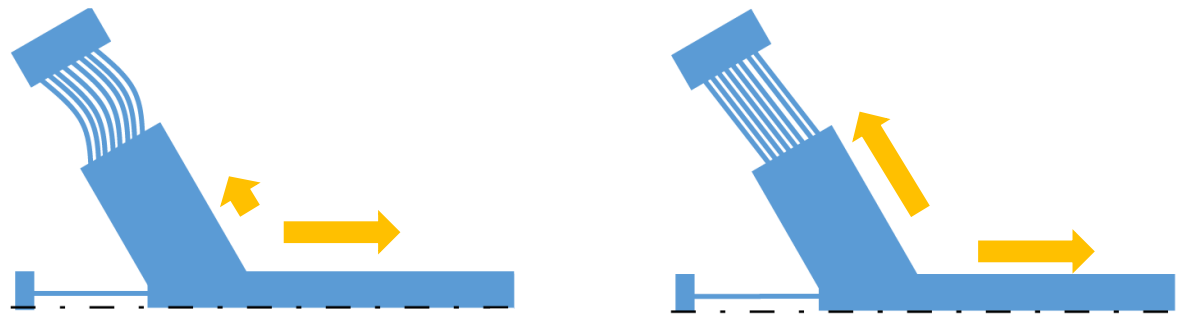
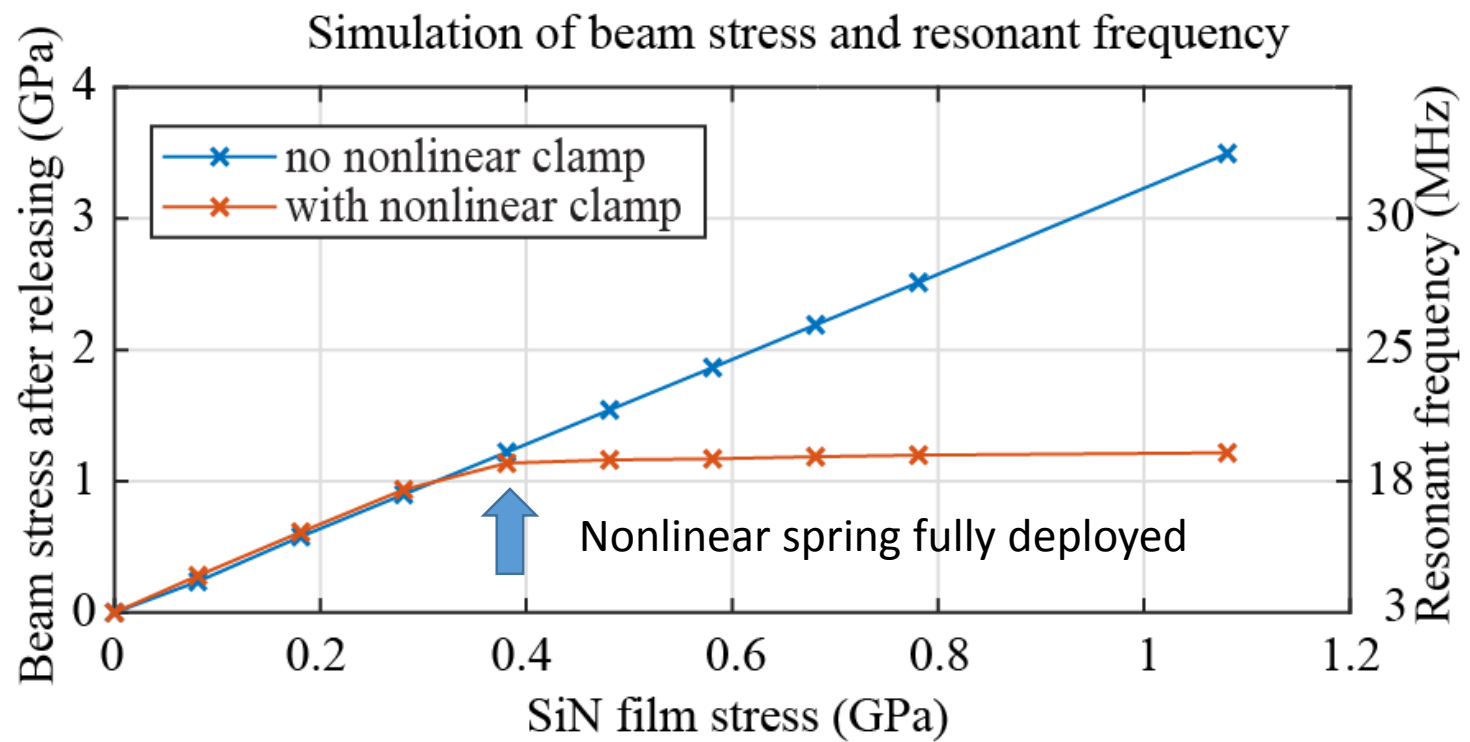


Stress Engineering – More Controllable?

- Nonlinear clamp design enable the frequency only determined by geometry
 - In regular tuning fork, the final beam stress/frequency determined by both intrinsic stress and the geometry



Stress Engineering – More Controllable?

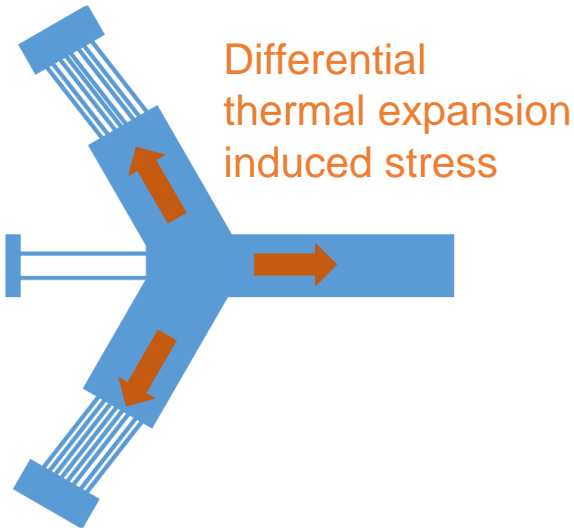


Temperature compensation

- With similar working principles, temperature sensitivity of vibration frequencies can also be engineered.
 - Temperature induced frequency fluctuation is mainly due to thermal expansion mismatch between device layer and substrate
 - Coefficient of Thermal Expansion (CTE) of Si: $2.6 \times 10^{-6} \text{ (K}^{-1}\text{)}$
 - CTE of LPCVD Si_3N_4 : $1.6 \times 10^{-6} \text{ (K}^{-1}\text{)}$



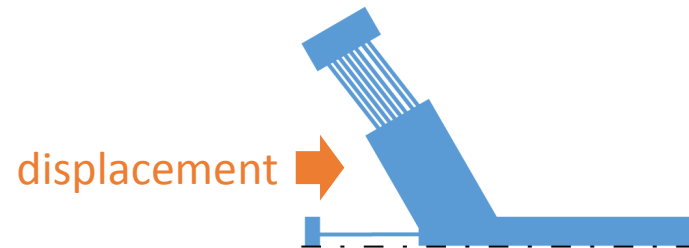
Beams are stretched/compressed



Beams length remain fixed

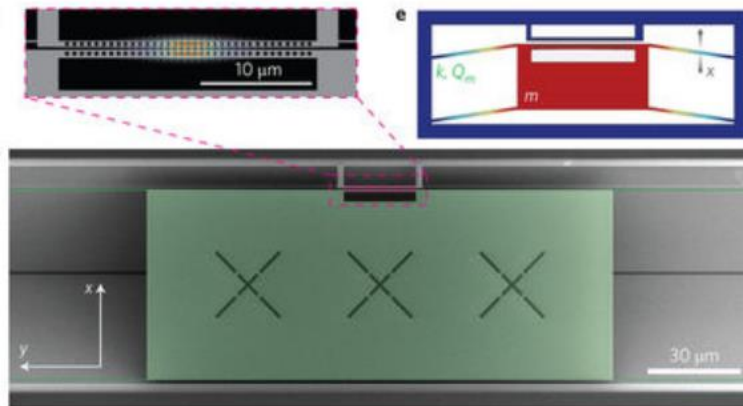
Allan deviation measurement

- Relative bias stability is $\approx 10^{-6}$ above 1 s averaging
 - Thermal dynamic limited
- Displacement uncertainty $\approx 0.2 \text{ pm}$

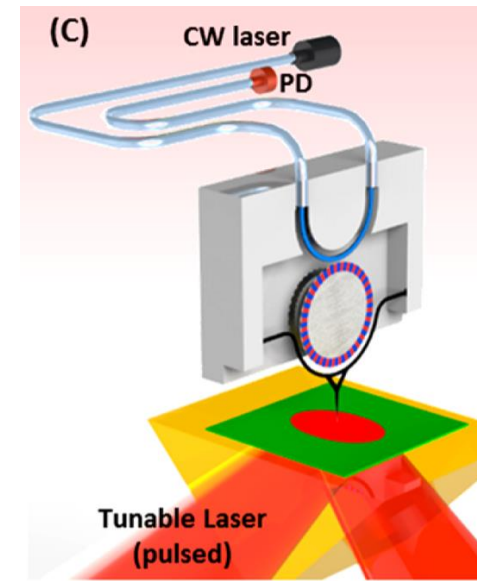


Summary

- Doubly clamped Si_3N_4 tuning fork cavity optomechanical sensors
 - Near-field optomechanical readout
 - High $f_m Q_m$ product resulting from tuning fork structure and increased beam stress
 - Geometry determined stress/frequency tuning
 - Temperature compensation with tunable temperature sensitivity
- Further development
 - Inertia sensing
 - Fully integration with photonic integrated circuit



Nature Photonics 6(11): 768-772



Nano Letters 17(9): 5587-5594

Thanks for your attention.
Questions?